

## GaAs MMIC Driver Amplifier Chip, 14-18 GHz

### Performance characteristics

- Frequency range: 14-18 GHz
- Small signal gain: 25dB
- Gain Flatness:  $\pm 1.0$ dB
- P-1: 27dBm
- Psat : 27.5dBm
- Power supply: +5 V /300mA
- 50Ohm input / output
- Chip size: QFN 5X5

### Product Introduction

GPA-1418D-CQ5 is a driver amplifier based on GaAs technology , with a frequency range of 14GHz~18GHz. GPA-1418D-CQ5 supports +5V power supply. This chip adopts 5 x 5 mm ceramic surface mount package, and the surface of the pin pad is gold-plated, which is suitable for reflow soldering installation process.

### Using the Limit Parameter

|                       |                |
|-----------------------|----------------|
| Maximum drain voltage | +7 V           |
| Maximum input power   | +20 dBm        |
| Operating temperature | -55 ~ + 125 °C |
| Storage temperature   | -65 ~ +150°C   |

Exceeding any of these maximum limits may cause permanent damage.

### Electrical performance parameters ( TA = +25°C , Vd = +5V )

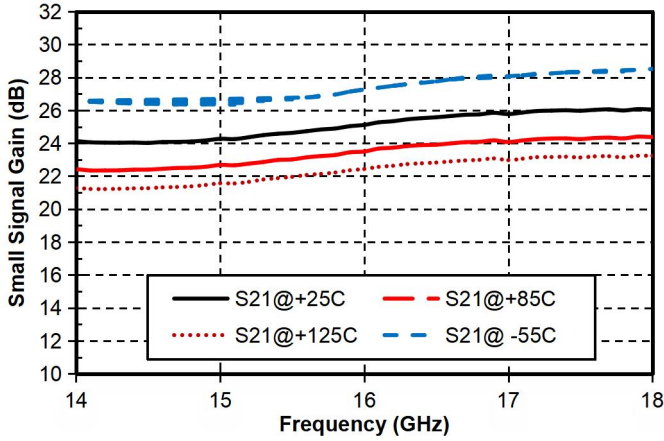
| Index              | Minimum | Typical Value | Maximum | Unit |
|--------------------|---------|---------------|---------|------|
| Frequency Range    | 14-18   |               |         | G Hz |
| Small Signal Gain  | -       | 25            | -       | dB   |
| Gain Flatness      |         | $\pm 1.0$     |         | dB   |
| P-1                |         | 27            |         | dBm  |
| Psat               | -       | 27.5          | -       | dBm  |
| Input return loss  | -       | 21            | -       | dB   |
| Output return loss | -       | 13            | -       | dB   |
| Quiescent Current  |         | 300           |         | mA   |

\* By tuning the Vg terminal voltage from -2V to 0V , the recommended Vg terminal voltage is -0.75V .

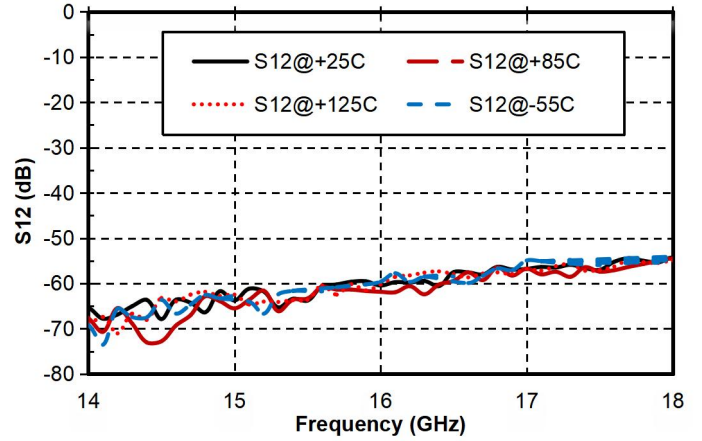
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Main index test curve @+5V

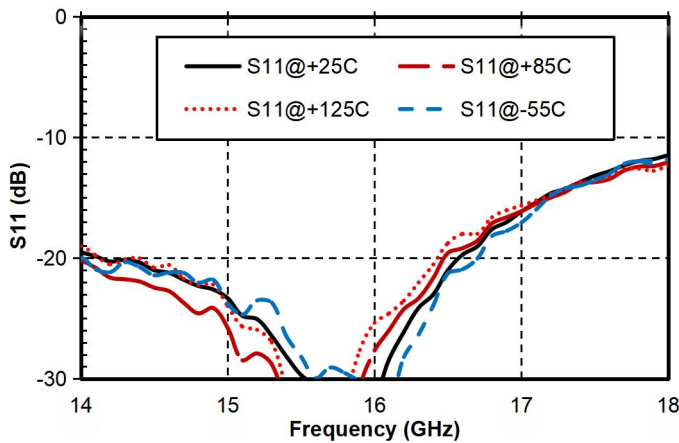
Gain vs. Frequency



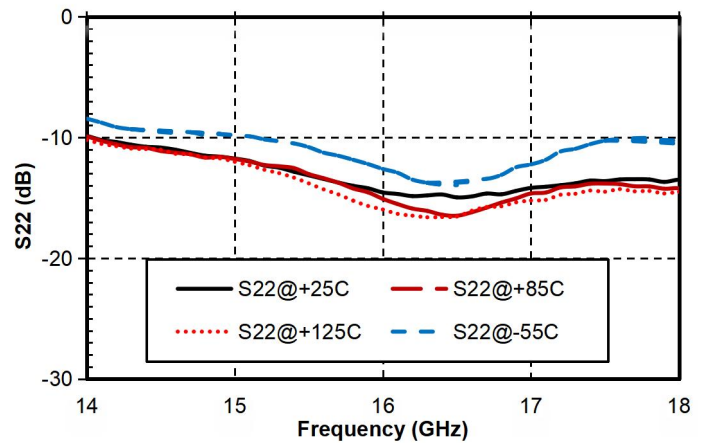
Reverse Isolation vs. Frequency



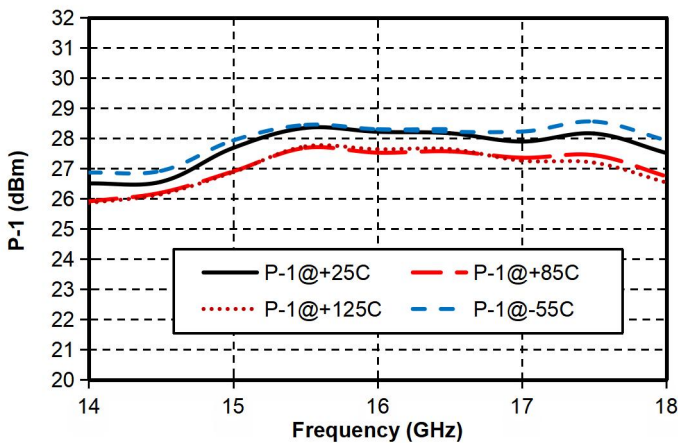
Input Return Loss vs. Frequency



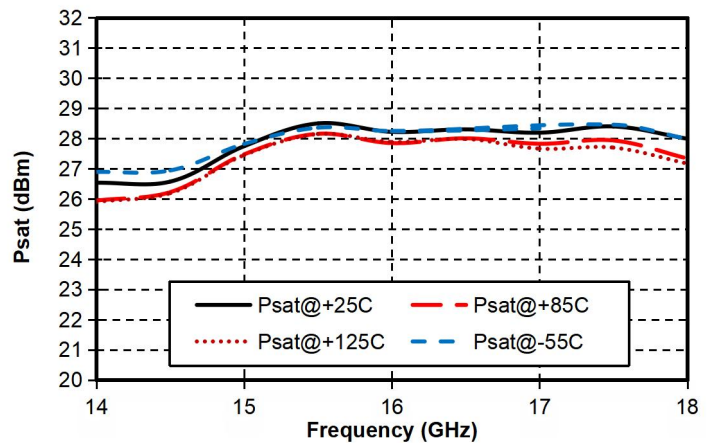
Output Return Loss vs. Frequency



P-1dB vs. Frequency

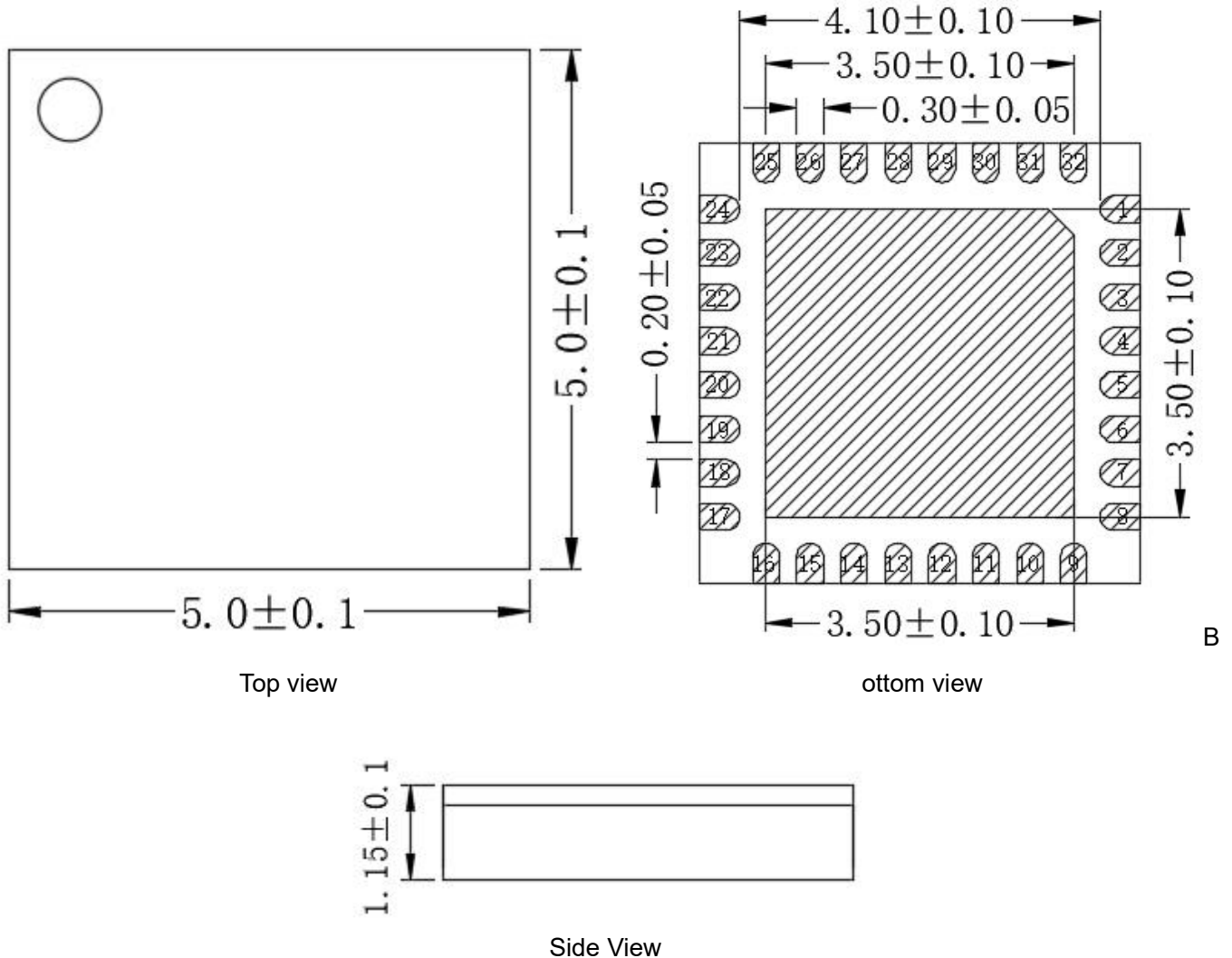


P sat vs. frequency



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Appearance structure



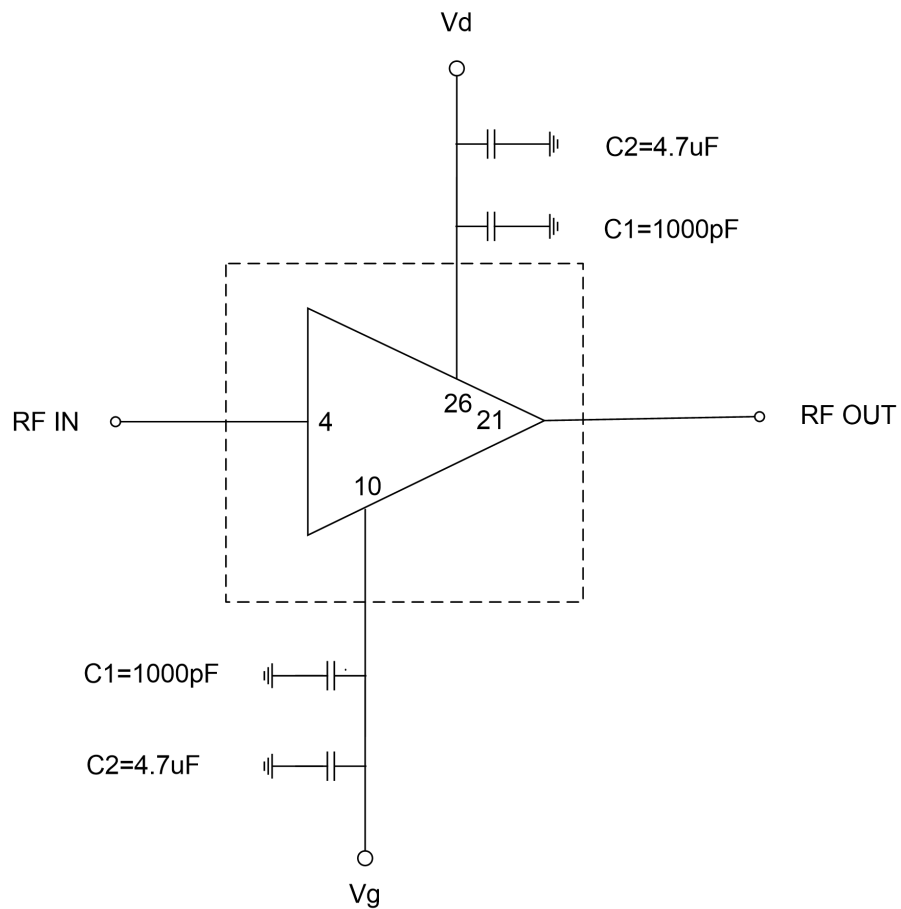
All units in the figures are millimeters .

| Pin Definition                    |                 |   |
|-----------------------------------|-----------------|---|
| Pin number                        | Function Symbol | Functional Description  |
| 4                                 | RFIN            | The signal input terminal is connected to a 50 ohm circuit, and no DC blocking capacitor is required  |
| 21                                | RFOUT           | The signal output terminal is connected to a 50 ohm circuit, and no DC blocking capacitor is required |
| 10                                | VG              | Amplifier Gate Bias   |
| 26                                | VD              | Amplifier Drain Bias  |
| 1-3 、 5-9 、 16-20 、<br>22-25 、 32 | GND             | The pins need to be well grounded to the RF and DC grounds  |
| Chip bottom                       | GND             | The bottom of the chip needs to be well grounded to RF  |

|       |    |                                      |
|-------|----|--------------------------------------|
|       |    | and DC                               |
| Other | NC | No welding required, can be grounded |

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### Recommended Circuit



### Precautions for use

- Sealing material : Ceramic material that meets ROHS standards
- Lead surface plating: gold, gold layer thickness 0.3um MIN
- Maximum reflow peak temperature: 260 °C